

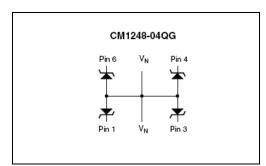
## Low Capacitance Transient Voltage Suppressors / ESD Protectors

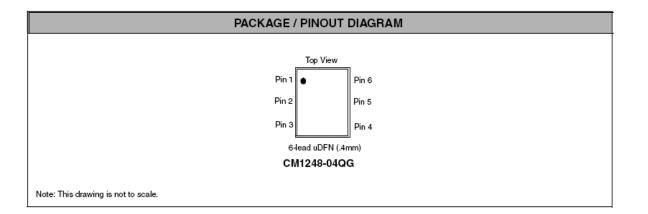
## CM1248-04QG

### Features

- Low I/O capacitance at 10pF at 0V
- In-system ESD protection to ±15kV contact discharge, per the IEC 61000-4-2 international standard
- Compact SMT package saves board space and facilitates layout in space-critical applications
- Each I/O pin can withstand over 1000 ESD strikes

### **Block Diagram**





PIN DESCRIPTIONS					
Pins	NAME	DESCRIPTION			
(Refer to package / pinout diagrams)	CHx	The cathode of the respective TVS diode, which should be connected to the node requiring transient voltage protection.			
(Refer to package / pinout diagrams)	V <sub>N</sub>	The anode of the TVS diodes.			

## **Ordering Information**

PART NUMBERING INFORMATION					
			Lead-free Finish		
Pins	Channels	Package	Ordering Part Num- ber <sup>1</sup>	Part Marking	
6	4	uDFN-0.4mm	CM1248-04QG	LR	

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

## Specifications

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	RATING	UNITS				
Storage Temperature Range	-65 to +150	°C				

STANDARD OPERATING CONDITIONS						
PARAMETER	RATING	UNITS				
Operating Temperature	-40 to +85	°C				

# CM1248-04QG

	ELECTRICAL OPERATING CHARACTERISTICS (NOTE 1)								
SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS			
C <sub>IN</sub>	Channel Input Capacitance	T <sub>A</sub> = 25 ℃, 0VDC, 1MHz; Note 2		10		pF			
		0VDC, 1MHz; Note1	7		15	pF			
$\Delta C_{_{\rm IN}}$	Differential Channel I/O to GND Capacitance	T <sub>A</sub> = 25 ℃, 2.5VDC, 1MHz; Note 2		0.19		pF			
V <sub>RSO</sub>	Reverse Stand-off Voltage	I <sub>R</sub> =10μA, T <sub>A</sub> = 25 °C	5.5			V			
		I <sub>R</sub> =1mA, T <sub>A</sub> = 25 ℃	6.1			V			
I <sub>leak</sub>	Leakage Current	V <sub>IN</sub> =5.0VDC, T <sub>A</sub> = 25 °C			0.25	μA			
		V <sub>IN</sub> =5.0VDC; Note 1			0.75	μΑ			
V <sub>SIG</sub>	Small Signal Clamp Voltage Positive Clamp Negative Clamp	I = 10mA, T <sub>A</sub> = 25 ℃ I = -10mA, T <sub>A</sub> = 25 ℃		6.8 -0.89		V V			
V <sub>ESD</sub>	ESD Withstand Voltage Contact Discharge per IEC 61000- 4-2 standard	Notes 2, 4 & 5; T <sub>A</sub> = 25 ℃	<u>+</u> 15			kV			
R <sub>D</sub>	Diode Dynamic Resistance Forward Conduction Reverse Conduction	T <sub>A</sub> = 25 ℃; Notes 2 & 3		0.57 1.36		Ω Ω			

Note 1: All parameters specified at  $T_A = -40 \ \text{C}$  to  $+85 \ \text{C}$  unless otherwise noted.

Note 2: These parameters guaranteed by design and characterization.

Note 3: Human Body Model per MIL-STD-883, Method 3015,  $C_{\text{Discharge}} = 100\text{pF}$ ,  $R_{\text{Discharge}} = 1.5\text{K}\Omega$ ,  $V_{\text{N}}$  grounded. Note 4: Standard IEC 61000-4-2 with  $C_{\text{Discharge}} = 150\text{pF}$ ,  $R_{\text{Discharge}} = 330\Omega$ ,  $V_{\text{N}}$  grounded.

Note 5: These measurements performed with no external capacitor on Pin<sub>x</sub>.

### **Performance Information**

### **Diode Capacitance**

Typical diode capacitance with respect to positive TVS cathode voltage (reverse voltage across the diode) is given in Diode Capacitance vs. Reverse Voltage .

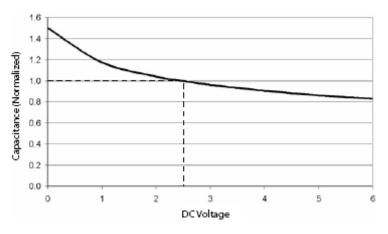
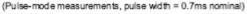


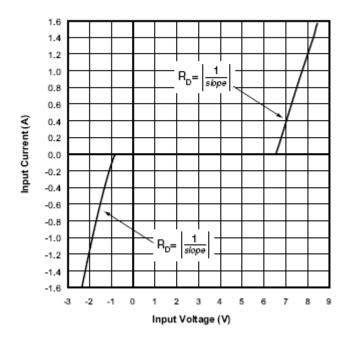
Figure 1. Diode Capacitance vs. Reverse Voltage

#### **Typical High Current Diode Characteristics**

Measurements are made in pulsed mode with a nominal pulse width of 0.7ms.

Typical Input VI Characteristics





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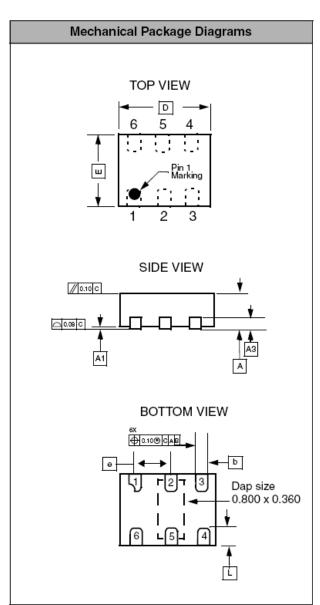
### **Mechanical Details**

### uDFN-06 Mechanical Specifications, 0.4mm

The 6-lead, 0.4mm pitch uDFN package dimensions are presented below.

PACKAGE DIMENSIONS							
Package		uDFN					
JEDEC No.	MO-229C <sup>*</sup>						
Leads	6						
Dim.	Millimeters				Inches		
	Min	Nom	Max	Min	Nom	Max	
А	0.450	0.500	0.550	0.018	0.020	0.022	
A1	0.000	0.020	0.050	0.000	0.001	0.002	
A3	0.100	0.150	0.200	0.004	0.006	0.008	
b	0.150	0.200	0.250	0.006	0.008	0.010	
D	1.150	1.250	1.350	0.045	0.049	0.053	
E	0.900	1.000	1.100	0.035	0.039	0.043	
е	0.350	0.400	0.450	0.014	0.016	0.018	
L	0.200	0.300	0.400	0.008	0.012	0.016	
# per tape and reel	3000 pieces						
Controlling dimension: millimeters							

<sup>\*</sup>This package is compliant with JEDEC standard MO-229C with the exception of the D, E, and L dimensions as called out in the table above.



Dimensions for 6-Lead, 0.4mm pitch uDFN package

## CM1248-04QG

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